Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
1.000 inches	
Overall Height:	
Between 1.719 inches and 1.781 inches	
Overall Width:	
1.000 inches	
Mounting Facility Quantity:	
1	
Mounting Method:	
Threaded stud	
Thready Qty Per Inch (tpi):	
32	
Thread Size:	
0.312 inches	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
264.0 forward voltage, total rms	
Current Rating Per Characteristic:	
5.50 amperes collector current, dc outside diameter	
Maximum Operating Tempurature Per Measurement Pe	oint:
85.0 degrees celsius junction	
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
2 uninsulated wire lead w/terminal lug	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	